Impact of nanostructured thin ZnO film in ultraviolet protection

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Abstract: Nanoscale ZnO is one of the best choices for ultraviolet (UV) protection, not only because of its antimicrobial properties but also due to its potential application for UV preservation. However, the behavior of nanostructured thin ZnO films and long-term effects of UV-radiation exposure have not been studied yet. In this study, we investigated the UV-protection ability of sol gel-derived thin ZnO films after different exposure times. Scanning electron microscopy, atomic force microscopy, and UV-visible optical spectroscopy were carried out to study the structure and optical properties of the ZnO films as a function of the UV-irradiation time. The results obtained showed that the prepared thin ZnO films were somewhat transparent under the visible wavelength region and protective against UV radiation. The UV-protection factor was 50+ for the prepared samples, indicating that they were excellent UV protectors. The deposited thin ZnO films demonstrated promising antibacterial potential and significant light absorbance in the UV range. The experimental results suggest that the synthesized samples have potential for applications in the health care field.

Keywords: ZnO, sol gel, thin film, UV protection

Introduction

In recent years, the destruction of the ozone layer in the earth’s atmosphere has led to an increased risk to human, plant, and animal life. Since ultraviolet (UV) radiation triggers the formation of free radicals, the long-term exposure of human skin to UV radiation can result in health issues, such as aging, DNA damage, skin reddening, acne, and even skin cancer.\textsuperscript{1} This indicates that UV radiation is one of the main sources of free radicals, leading to direct biological damage and different types of cancer. In addition, UV radiation-induced damage can be associated with the discoloration of dyes and pigments, weathering, yellowing of plastics, and loss of gloss and mechanical properties (cracking) as well.\textsuperscript{2} Consequently, several products must be protected to sustain long periods under UV radiation.\textsuperscript{3–5} Therefore, the study and development of UV-protective materials has become a very important issue. To be a UV-absorbing material, several features, including high transparency, high UV-absorption coefficient, high photostability, and affordability, must be present. There are inorganic and organic UV absorbers commercially available. Organic UV absorbers have been used to protect organic materials against UV radiation. However, the low stability of the polymer matrices commonly used to embed the absorbers upon UV irradiation limits their application severely.\textsuperscript{6,7} In order to provide an effective protection against UV radiation, one of the requirements of UV-absorber molecules is the ability to transform the absorbed radiation energy in less damaging thermal energy via a photophysical process.\textsuperscript{8} With regard to delamination and the time it takes to occur (closely related to...
the dose of UV radiation reaching the substrate or primer), organic UV absorbers are not permanent, and their photo-degradation is an important factor in determining coating lifetime. Inorganic materials based on metal oxide semiconductors can efficiently absorb UV radiation and exhibit good heat-resistance properties. They are used as transparent inorganic matrices or embedded in polymers as UV absorbers. It should be noted that the use of nanoscale inorganic materials leads to an increase in stability of protective coatings, with highly efficient UV absorption. Naturally, the band gap of nanoscale inorganic materials must be suitable for UV-radiation absorption. For example, TiO₂ has a band gap with an optical absorption in the ~310–400 nm-wavelength region, and its absorption does not cover the entire UV region (especially the dangerous region of 290–350 nm). On the other hand, CeO₂ (E₉=3.1 eV) can absorb light in the entire UV region, but its strong yellowish coloration limits its use in color-sensitive applications, such as artwork protection. However, ZnO with a wide band gap (E₉=3.37 eV, corresponding to 376 nm) has unique electrooptical properties and efficient UV absorptivity combined with good transparency in the visible range (because it absorbs light that matches or exceeds its band-gap energy). It can be used as a packaging material for UV white-light-emitting diodes that require both high visible-light (>400 nm) transparency and high UV-light (<400 nm) resistance. As reported by Li et al., high UV-light resistance of packaging materials may be achieved via structural design of transparent epoxies and addition of organic or inorganic UV-light absorbents. UV absorbents (eg, ZnO) do not typically migrate in a polymeric matrix, and their photostability and thermal stability provide advantages, such as being stable and nonmigratory within a matrix, and thus potentially impart better effectiveness and longer service life. In comparison with other UV-protection candidates, ZnO is advantageous, due to its protection over long periods, broadband protection, and nonwhitening of skin. The use of materials with UV-protection properties is typically based on optical scattering and/or absorption. On the other hand, the UV-blocking ability of nanoscale ZnO also depends on its size and morphology. Therefore, ZnO nanoparticles with different sizes and morphologies have different UV-blocking properties. ZnO nanoparticles absorb UV radiation and transform it in harmless infrared light, which is dissipated as heat. It must be noted that the inability to achieve 100% efficiency in heat conversion of UV light leads to the creation of free radicals and results in oxidative damage to DNA. Several studies have reported improved UV blocking for materials containing ZnO nanoparticles. Recently, an anti-UV fiber coated with ZnO nanoparticles was developed, possessing UV-shielding, antibacterial, and sterilization properties. Moreover, nanosize ZnO particles deposited on cotton and polyester/cotton products indicate a significant improvement in UV-absorbing activity, with a UV-protection factor (UPF) of 15. Tsuchi studied the photoactivity of ZnO nanoparticles via impurity doping, and reported that ZnO is a safe UV-blocking agent for several applications. In other similar studies, a multilayer ZnO film was deposited on cotton, providing a UPF of ~12. In order to increase UPF value, copolymer/ZnO has been coated on cotton textiles. The morphology of these compounds is very important to determine their utilization as UV-radiation absorbers. Nanostructured thin ZnO films are mainly used as UV-protection filters, installed in devices and packages. However, thin ZnO films have high transparency in the visible range and high absorption in the UV range. Recently, it has been reported that a multilayer ZnO film deposited on cotton could provide a UPF of ~12. To achieve a UPF of 50+, a copolymer film coated on cotton textile was used. In this study, a simple and low-cost method was developed to prepare transparent nanoscale thin ZnO films with a UPF of 50+. The synthesized sample can be easily coated on different types of plastics, textiles, glasses, cosmetics, and other products for UV protection. Therefore, our investigation can be applied in the future to other systems.

**Materials and methods**

In this study, thin ZnO films were prepared using a sol-gel method on glass substrates, and the structural and optical properties of these films were studied using X-ray diffraction (XRD), atomic force microscopy (AFM), and UV-visible spectrophotometry. For the ZnO-nanoparticle preparation, the precursor used was zinc acetate dihydrate (ZnAc; Zn[C₂H₃O₂]₂ ⋅ 2H₂O, 99.5%; Merck Millipore, Billerica, MA, USA), and indium(III) chloride, aluminum acetate, and lithium acetate were used as doping sources. Pure ethanol and triethanolamine (TEA) were used as solvent and stabilizer, respectively. Indium(III) chloride, aluminum acetate, and lithium acetate were purchased from Sigma-Aldrich (St Louis, MO, USA). Reagent-grade ethanol with 99.9% purity was used. The triethanolamine/ZnAc molar ratio was maintained at 2:5. Additional details of the preparation process have been reported elsewhere. The nanostructured thin ZnO films were prepared using a dip-coating method. In this approach, the glass substrates were washed with acetone and absolute ethanol for 10 minutes. The film deposition was carried out in air at room temperature using a dip-coating method on
the substrate at a controlled speed of 1.8 cm/min. After each coating, the films were preheated at 70°C for 1 hour and postheated at 500°C for 2 hours. UV spectra were measured using UV-visible spectrophotometry (Cary 500; Agilent Technologies, Santa Clara, CA, USA) to study the optical properties of the films. XRD patterns were obtained with a PW 3050-60 (PANalytical, Almelo, the Netherlands) at room temperature, and 2θ values were measured between 10° and 90° to investigate the crystal structure. The incident wavelength was 1.54059 Å. To study the morphology, roughness, and grain size of the thin ZnO film, an AFM CP Research (Veeco, Plainview, NY, USA) was used. To study the surface morphology and grain size of the synthesized thin In-doped ZnO (IZO) film, scanning electron microscopy (SEM) was used. To determine the chemical homogeneity and composition of the thin ZnO film, energy-dispersive X-ray spectroscopy (EDX) analysis was also carried out. The samples were irradiated with broad radiation from a UV source (Bio-Sun; Vilber, Collégien, France) according to the ideal conditions listed for UV protection (ISO 2443:2012).

Results and discussion

As reported in previous studies,33–36 both sol and dopant ion concentrations affect the optical properties of thin ZnO films. Moreover, the absorbance peak of ZnO sol changed considerably due to ZnAc-concentration variation. Therefore, three sols with different ZnAc concentrations (1, 1.5, and 2 M) were synthesized. Figure 1 shows that an increase in ZnAc concentration led to an increase in the absorption peak of the prepared sol. As such, the best ZnAc concentration for preparing thin films with high absorbance at the UV-wavelength region was 2 M. Samples were also prepared with concentrations higher than 2 M, but the optical transparency of the thin films decreased. In addition, to improve the optical properties of the thin ZnO films, specific amounts of impurities were used. We selected the solid-solubility limit for each impurity, because the maximum concentration of dopant ion (concentration in a perfect crystalline structure of host material) is limited by its solid solubility. This concentration varies in polycrystalline semiconductors, because defects and grain boundaries can act as deposition sites, resulting in an increase of dopant concentration.37

Figure 2 shows the absorption and transmission spectra of the ZnO sols with various impurities. From Figure 2A, it can be observed that the Li- and Al-doped ZnO sols did not absorb ~20% of UV light, indicating that they are not suitable for UV protection; however, both IZO and pure ZnO sols had low transmission in the UV region (<2%). Therefore, the IZO and ZnO sols might be good candidates for UV-protection materials. All samples were transparent in the 400–900 nm wavelength. In order to study the impact of the IZO and nanostructured pure thin ZnO films on UV protection, several samples were prepared using a dip-coating method. The optical properties of the thin films were compared before and after UV exposure. Moreover, their effectiveness in shielding UV radiation was evaluated by measuring UV absorption, transmission, and reflection. The UV-visible absorption, transmission, and reflection spectra of the thin ZnO and IZO films annealed at 50°C can be observed in Figures 3 and 4, respectively. The samples were exposed to UV radiation for 15 and 25 hours (Bio-Sun), in accordance with the ideal conditions listed for UV protection (ISO 2443:2012) in air. The thin ZnO films had strong absorbance at the UVA wavelength (310–385 nm) and exhibited high transmission in the visible region, as shown in Figure 3. These optical properties are very important in terms of commercial beautification, especially in the artificial-skin industry for UV protection. The absorbance variation for the thin ZnO film was not significant after UV treatment for 15 and 25 hours (Figure 3A). However, transmittance variation of the thin ZnO film was noticeable after the same UV treatment (Figure 3B). It can be observed from Figure 3C that the reflectance of the thin ZnO film was affected by UV radiation and increased after UV exposure. These variations might have been related to the modifications in surface morphology. Similarly to thin ZnO film, the absorbance variation of the thin IZO film was not significant after UV treatment for 15 and 25 hours (Figure 4A). IZO films exposed to the UV source showed a slight decrease in transmittance (Figure 4B). Reflectance increased in the UVA region (Figure 4C). Transmission decrease was observed for the visible region.
results from variations in surface roughness induced by light scattering. The optical properties of the samples before and after UV exposure are described by a triple action: ~1%–2% of UV rays are transmitted (300–400 nm), 85%–95% of infrared rays (300–400 nm) are absorbed, and 2%–20% of UV rays are reflected (300–400 nm). To evaluate the optical properties of the thin ZnO and IZO films before and after UV irradiation, absorbance, transmission, and reflectance data of the samples were compared. The obtained results for the wavelength of 300–400 nm are shown in Figure 5. The amount of UV energy transmitted through the thin ZnO film increased, but it was not significantly influenced by long-term
**Figure 4** (A) Absorption, (B) transmission (T), and (C) reflection (Ref) spectra of thin IZO films.

**Abbreviations:** IZO, In-doped ZnO; UV, ultraviolet.

**Figure 5** Approximate values of (A) transmission (T), (B) absorption, and (C) reflection (Ref) versus time of UV exposure.

**Abbreviations:** UV, ultraviolet; IZO, In-doped ZnO.
UV exposure, as shown in Figure 5A. The thin ZnO film absorbed UV radiation over long periods, transmitting $>$1% of UV light. The opposite behavior was exhibited by the thin IZO film. This film absorbed UV radiation, and after UV treatment the amount of UV energy transmitted through the film decreased, transmitting $<$2% of UV rays; the reflectance increase for the thin IZO film was smaller than that of the thin ZnO film. It was expected that longer UV-exposure times would lead to a constant absorbance value for both samples (ZnO and IZO), corresponding to the saturation state (see Figure 5B). It can be concluded that the presence of In improves UV filtering after increasing UV-exposure time. However, IZO-absorbance values were smaller compared to ZnO, which was due to the stress caused by the presence of In in the structure. The UV-coverage ability of the thin films depends primarily on the grain size. Some studies have shown that UV-blocking capacity decreases for grain sizes above 0.1 $\mu$m.$^{38,39}$ To evaluate further these materials, the optical band gap of the thin films was determined. The direct energy band gap of the thin films was calculated using Equations 1–3:

$$ A = \alpha d = -\ln T $$

$$ \alpha h \nu = B (E_g - h \nu)^{3/2} $$

$$ B = \frac{q^2 (2 m^*_e m^*_h)}{m^*_e c^2 h^2 (m^*_e + m^*_h)^{3/2}}, $$

where $A$ is the absorbance, $d$ the film thickness, $T$ the transmission of the thin films, $\alpha$ the optical absorption coefficient, $h \nu$ the photon energy, $E_g$ is the direct band-gap energy, and $B$ a constant. The optical absorption coefficient can be determined by plotting $(\alpha h \nu)^2$ as a function of the photon energy and extrapolating the linear portion of the curve to zero.$^{40}$ The $E_g$ value of the samples was calculated for the thin ZnO (3.29, 3.28, and 3.24 eV) and IZO films (3.28, 3.26, and 3.24) after different UV-exposure times (0, 15, and 25 hours), respectively. No significant difference was observed in the energy band gap between the unirradiated and the UV-irradiated samples. Nevertheless, it appears that the band gap decreased slightly. The SEM image and EDX spectrum of the In$^{3+}$-doped thin ZnO film deposited on the glass substrate are presented in Figure 6. The SEM image shows that the deposited thin ZnO film had a polycrystalline structure and uniform morphology. The EDX pattern of the composite demonstrates the existence of In$^{3+}$ ions in the film. The presence of Si ions is due to the glass substrate. The XRD pattern of the thin IZO film is illustrated in the inset of Figure 6B. Using the Scherrer equation, the average grain size was 45 nm. The surface morphology of the prepared thin films (before and after UV exposure) was characterized by AFM, as shown in Figure 7. It was observed that the surface morphology of the thin film was modified and affected by the UV radiation. Indeed, UV radiation causes distortions and leads to surface modifications. UV exposure induced structural damage.$^{41}$ This can be explained by the formation of disordered regions around the crystallites, the increase in particle size, and the modification in surface morphology of the film after longer UV-irradiation times. Surface roughness, as a component of the surface texture, gives an indication about the quality of the surface and light scattering of the samples. An increase of In$^{3+}$ ion concentration results in increased surface roughness of the thin ZnO films. The root mean square of the thin films also increased, due to the increased UV-exposure time. By increasing UV-exposure time, the surface morphology of the thin IZO and ZnO films was modified due to particle-size increase. The results showed an increase in surface reflection with the modification in surface morphology of the thin films. Other studies have shown that UVA protection with small ZnO particles is low. However, with varying size and morphology at the nanoscale, the UV-blocking behavior of nanoscale ZnO varies.$^{42,43}$ It was observed that the layer roughness increased (after UV exposure), leading to higher UV reflection and preventing the penetration of UV rays in the food (see Figure 8). The absorbance of the thin IZO films (for the UVA region) increased with increasing size, roughness, and UV irradiation, while absorbance decreased for the thin ZnO films. The root-mean-square roughness values of the samples are shown in Table 1. To confirm that the prepared samples were suitable for UV protection, their UPF was determined. This is a numerical rating to express UV radiation-blocking effectiveness. UPF ratings indicate how much the material reduces UV exposure. The highest UPF rating is 50+, which provides “excellent” protection from UV radiation. The UPF categories and UPF ratings for fabrics and coverings are shown in Table 2. The UPF can be calculated as follows:$^{44,45}$

$$ \text{UVA protection factor} = \frac{\sum_{400 \text{nm}}^{400 \text{nm}} E \cdot S \cdot T}{\sum_{1200 \text{nm}}^{1200 \text{nm}} E \cdot S \cdot T}, $$

where $\lambda$ is the wavelength in the 320–400 nm range, $S_{\lambda}$ the solar spectral irradiance at wavelength $\lambda$, $E_{\lambda}$ the energy
Figure 6 (A) SEM image and (B) energy-dispersive X-ray pattern of thin IZO film. The inset of (B) shows the X-ray diffraction pattern of IZO-TF.

Abbreviations: SEM, scanning electron microscopy; IZO, In-doped ZnO; TF, thin film.

Figure 7 (Continued)

ZnO
RMS roughness = 7.15 nm
Particle size: 55 nm

IZO
RMS roughness = 8.42 nm
Particle size: 76 nm
Table 1  RMS roughness values of samples according to UV exposure

<table>
<thead>
<tr>
<th>Thin films</th>
<th>ZnO: RMS (nm)</th>
<th>IZO: RMS (nm)</th>
</tr>
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<tbody>
<tr>
<td>Before UV exposure</td>
<td>7.15</td>
<td>8.42</td>
</tr>
<tr>
<td>15 hours' UV exposure</td>
<td>11.7</td>
<td>23.81</td>
</tr>
<tr>
<td>25 hours' UV exposure</td>
<td>13.23</td>
<td>28.23</td>
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</table>

Abbreviations: RMS, root mean square; UV, ultraviolet; IZO, In-doped ZnO.

Figure 7 AFM images of thin ZnO and IZO films before and after UV exposure.
Abbreviations: AFM, atomic force microscopy; IZO, In-doped ZnO; UV, ultraviolet; RMS, root mean square.

Figure 8  The penetration of UV rays into the materials. Without (A) and with (B) UV shielding.
Abbreviation: UV, ultraviolet.

thermal spectral effectiveness at wavelength \( \lambda \), and \( T_\lambda \) the product transmission at wavelength \( \lambda \). The UPF data were calculated based on the reference spectra according to the American Association of Textile Chemists and Colorists test method 183.\(^{46}\) UPF values for the UVA range were calculated according to Equation 4, and were \(~40–45\) and \(~45–50\) for the ZnO and IZO samples, respectively. The In-loaded samples had higher protection against UV radiation, and presented “excellent” UV shielding. These results confirmed that the best protection against UV radiation was obtained with nanostructured thin IZO films. Therefore, we can protect different products (to sustain long periods under UV radiation) by using a protective coating. Skin protection against UV radiation can also be achieved by textiles coated with IZO.\(^{47}\) This kind of protection can be used for both smart and artificial skins.\(^{48}\) Occasionally, people that are
exposed to the sun do not have access to shade or sunscreen, or might have a particular sensitivity to these sunscreens; in this case, the best solution is using the appropriate cover for our skin. An artificial skin can be used for protecting the skin temporarily. There are several different types of artificial skins, ranging from sheets of human skin grown from the patient’s own cells to others entirely synthetic, designed to act as a support so that the body can grow its own skin as it heals. Manufacturing transparent coatings (similar artificial skins), based on UV-absorbing nanoparticles, can represent a big step in the prevention of skin cancer. As we have mentioned, UV radiation is one of the most important factors in maintaining skin health, so it is better to know more about UV radiation.

**Conclusion**

In summary, transparent thin ZnO films with high UV light-shielding efficiency were reported in this study using a simple and low-cost method. A highly concentrated pure ZnO sol (2 M) was prepared with In impurities as a suitable candidate to study optical properties against UV irradiation. The effect of UV irradiation on the optical properties of the nanostructured thin ZnO and IZO films was investigated. The obtained results showed that the prepared thin IZO films were somewhat transparent under the visible-wavelength region and were protective against UV radiation. The UPF was 50+ for the prepared samples, showing excellent UV protection. We can postulate that thin IZO film can be used as a UV-blocking material and find application as a UV absorber in cosmetics, packages, textiles, and protective coatings.

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**Disclosure**

The authors report no conflicts of interest in this work.

**Table 2 Standards for UPF ratings on fabric and covering**

<table>
<thead>
<tr>
<th>UPF rating</th>
<th>Protection category</th>
<th>% UV radiation blocked</th>
<th>% UV radiation transmission</th>
</tr>
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<tr>
<td>15, 20</td>
<td>Good</td>
<td>93.3–95.9</td>
<td>6.7–4.2</td>
</tr>
<tr>
<td>25, 30, 35</td>
<td>Very good</td>
<td>96–97.4</td>
<td>4.1–2.6</td>
</tr>
<tr>
<td>40, 45, 50, 50+</td>
<td>Excellent</td>
<td>≥97.5</td>
<td>≤2.5</td>
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</tbody>
</table>

Abbreviations: UPF, UV-protection factor; UV, ultraviolet.

**References**